



Data Sheet

Trans MOSFET N-CH 100V 10A 8Pin PQFN EP T/R

Manufacturers ON Semiconductor, LLC

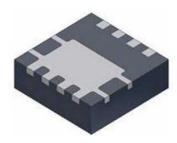
Package/Case 8-PowerWDFN

Product Type Transistors

RoHS Green

Lifecycle

Please submit RFQ for FDMD86100 or Email to us: sales@ovaga.com We will contact you in 12 hours.



Images are for reference only



General Description

This package integrates two N-Channel devices connected internally in common-source configuration and incorporates Shielded Gate technology. This enables very low package parasitics and optimized thermal path to the common source pad on the bottom. Provides a very small footprint (5 x 6 mm) for higher power density.

Features

Common source configuration to eliminate PCB routing

Large source pad on bottom of package for enhanced thermals

Application

ONSEMI

Related Products



FDC645N

ON Semiconductor, LLC

SSOT-6



FDC6305N

ON Semiconductor, LLC

SSOT-6



FDC637BNZ

ON Semiconductor, LLC

SSOT-6



FDC602P

ON Semiconductor, LLC

SOT163



FDD8647L ON Semiconductor, LLC TO-252-3



ON Semiconductor, LLC TO-263

FDB070AN06A0



FDD5N50NZTM
ON Semiconductor, LLC
TO-252



FDD3670 ON Semiconductor, LLC TO-252AA